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Front Matter: Volume 9174

, "Front Matter: Volume 9174," Proc. SPIE 9174, Nanoepitaxy: Materials and Devices VI, 917401 (17 September 2014); doi: 10.1117/12.2081273

SPIE.

Event: SPIE NanoScience + Engineering, 2014, San Diego, California, United States

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Nanoepitaxy: Materials and Devices VI

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Editors

19–21 August 2014
San Diego, California, United States

Sponsored and Published by
SPIE

Volume 9174

Proceedings of SPIE 0277-786X, V. 9174

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Nanoepitaxy: Materials and Devices VI, edited by Nobuhiko P. Kobayashi,
A. Alec Talin, Albert V. Davydov, M. Saif Islam, Proc. of SPIE Vol. 9174, 917401
© 2014 SPIE · CCC code: 0277-786X/14/\$18 · doi: 10.1117/12.2081273

Proc. of SPIE Vol. 9174 917401-1

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Author(s), "Title of Paper," in *Nanoepitaxy: Materials and Devices VI*, edited by Nobuhiko P. Kobayashi, A. Alec Talin, Albert V. Davydov, M. Saif Islam, Proceedings of SPIE Vol. 9174 (SPIE, Bellingham, WA, 2014) Article CID Number.

ISSN: 0277-786X

ISBN: 9781628412017

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

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The CID Number appears on each page of the manuscript. The complete citation is used on the first page, and an abbreviated version on subsequent pages. Numbers in the index correspond to the last two digits of the six-digit CID Number.

Contents

v	Authors
vii	Conference Committee

GROUP III-V AND IV NANOSTRUCTURES I

9174 05	Direct band gap wurtzite GaP nanowires for LEDs and quantum devices (Invited Paper) [9174-4]
---------	---

1D NANOSTRUCTURES I

9174 07	Silicon epitaxy in nanoscale for photovoltaic applications (Invited Paper) [9174-6]
---------	--

GROUP III-NITRIDE NANOSTRUCTURES

9174 0G	Bulk GaN and its application as substrates in building quantum nanostructures for some electronic and optoelectronic devices (Invited Paper) [9174-15]
---------	---

2D NANOSTRUCTURES AND DEVICES I

9174 0H	Metalorganic chemical vapor deposition of Bi₂Se₃ thin films for topological insulator applications (Invited Paper) [9174-16]
---------	---

GROUP III-V AND IV NANOSTRUCTURES II

9174 0O	Magnetic doping of Ge-quantum dots: growth studies exploring the feasibility of modulating QD properties (Invited Paper) [9174-23]
9174 0P	GaAs-AlGaAs core-shell nanowire arrays: correlating MOVPE growth and luminescence properties (Invited Paper) [9174-24]

2D NANOSTRUCTURES AND DEVICES II

9174 0S	Nanoelectronic synaptic devices and materials for brain-inspired computational architectures (Invited Paper) [9174-27]
9174 0T	Investigation on resistive switching characteristics of ZnO thin film (Invited Paper) [9174-28]

1D NANOSTRUCTURES II

- 9174 0Z **Acid-leached α -MnO₂ nanowires for electrochemical energy storage (Invited Paper)**
[9174-34]
- 9174 11 **SAD-GLAD core-shell nanorod arrays for fuel cell, photodetector, and solar cell electrode applications** [9174-36]

3D HETEROGENEOUS MATERIALS AND DEVICE INTEGRATION

- 9174 13 **Understanding and optimization of the sensitivity of nanoscale FET-based biosensors (Invited Paper)** [9174-38]

Authors

Numbers in the index correspond to the last two digits of the six-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first four digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Assali, S., 05
Bakkers, E. P. A. M., 05
Bockowski, M., 0G
Brom, Joseph E., 0H
Byles, Bryan, 0Z
Cansizoglu, H., 11
Cansizoglu, M. F., 11
Chui, Chi On, 13
Dayeh, Shadi A., 07
Deng, Hong, 0T
Evans, David, 07
Haverkort, J. E. M., 05
Jha, Rashmi, 0S
Karabacak, T., 11
Kariuki, N., 11
Khudhayer, W. J., 11
Kriegner, D., 05
Li, Chunfu, 0T
Lovergine, Nico, 0P
Mandal, Saptarshi, 0S
Miccoli, Ilio, 0P
Myers, D. J., 11
Nguyen, Binh-Minh, 07
Nolph, Christopher A., 0O
Picraux, S. T., 07
Plissard, S., 05
Pomerantseva, Ekaterina, 0Z
Prete, Paola, 0P
Ramalingam, Gopalakrishnan, 0O
Redwing, Joan M., 0H
Reinke, Petra, 0O
Schuele, Paul, 07
Shaikh, A. U., 11
Shoorideh, Kaveh, 13
Simov, Kiril R., 0O
Stangl, J., 05
Subramanian, Arunkumar, 0Z
Verheijen, M. A., 05
Wei, Min, 0T
Wen, Guangjun, 0T
Yang, Fan, 0T
Yoo, Jinkyong, 07
Yurukcu, M., 11
Zardo, I., 05

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- 2 1D Nanostructures I
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- 4 2D Nanostructures and Devices I
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- 5 Organic-Inorganic Integration
A. Alec Talin, Sandia National Laboratories (United States)
- 6 Group III-V and IV Nanostructures II
Joan M. Redwing, The Pennsylvania State University (United States)
- 7 2D Nanostructures and Devices II
Ekaterina Pomerantseva, Drexel University (United States)
- 8 1D Nanostructures II
Albert V. Davydov, National Institute of Standards and Technology
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- 9 3D Heterogeneous Materials and Device Integration
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